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1 INTRODUCTION

MTCS – TIAM2 is a True Colour Sensor IC with integrated amplifier. The IC is packaged into a FR4-board / plastic package. It includes XYZ (RGB) filters and is specialized for colour measurements based on the tri-stimulus function.

The True Colour Sensors are made of 19×3 photo diodes (special PIN silicon technology with extended sensibility) integrated on chip. The diodes are carried out as segments of a multiple-element hexagonal matrix structure with the diameter of 2,0 mm.

The design as Si-PIN photo diodes allows signal frequencies up to high-range. In order to achieve a small cross talk between the photodiodes the individual sectors were separated from each other by additional structures.

Each of these photodiodes is sensitized with new dielectric spectral filter (named True Colour Filter¹) for its colour range, preferably for the primary colour standard CIE (Commission Internationale de l'Eclairage or International Commission on Illumination) colour space.

The TIAM2 comes with an integrated multi-channel amplifier (see also the data sheet MTI04 of MAZeT) with the ability to set customized the transimpedance at eight different levels. It gives the customer a wide area in which to accommodate all application requirements in light power and frequency.

2 APPLICATION

- General Colour detection and measurements
- Consumer appliances
- Portable colour detector/reader
- RGB-LCD backlight monitors
- Regulation of RGB-power LEDs
- Detector for various light sources

3 FEATURES

Dielectric filters guaranties the good optical properties of the colour sensors, such as:

- high transmission
- slight ageing of the filter
- high temperature stability
- high signal frequency
- reduced cross talk
- small size
- alike tri-stimulus interference filter for colour measurement to DIN 5033 (CIE 1931)
- LCC package
- RoHS-conform



Figure 1: TIAM2 - Var. A



Figure 2: TIAM2 - Var. B

¹ The new generation of JENCOLOUR sensors is committed to implementing (see relative sensitivity) the standard distribution functions as defined under DIN 5033 Part 2 – Color Measurement; CIE 1931 Standard Colorimetric Systems. This implementation method allows colors to be determined according to the three-range procedure that is defined in part 6 of DIN 5033.

VERSION DATA SHEET MTCS - TIAM2 NO. ISSUE APPROVED 1 V 1.4 2007-03-20 **4 BLOCK DIAGRAM** Amplifier MTI04C I/U SW1 SW1 SW2 SW2 Ξ SW3 SW3 XYZ - detector SW4 X - Function MTCSiC I TR ^{du} IN1 OUT1 rt 🖯 4 4 4 4 A I RT U RT IN2 OUT2 ≻ I_BL U_BL IN3 OUT 3 ^{bl} Ν gn 🖯 I_{GN} U_GN OUT4 IN4 PD PD U1 +3_3V VDD VREF 2.4VREF GND М U2

Figure 3: on Chip detector MTCSi and amplifier MTI04C



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5 SPECTRAL RESPONSE



Figure 5: typical (relative) sensitivity (XYZ) of the colour sensor2, scanned by width broadband light (FWHM 30nm)



Figure 6: typical (relative) sensitivity (XYZ) of the colour sensor3 scanned by narrow-band light (FWHM 3nm)

² Typical characteristic sensitivity; scanned by monochromatic light with FWHM 27nm	
³ Typical characteristic sensitivity; scanned by monochromatic light with FWHM 2nm	

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6 DESCRIPTION OF INTERFACE

signal name	typ.	a/dª	function
VDD	input	a/d	power supply
GND	input	a/d	power supply
VREF	input	а	reference voltage
SW1	input	d	input 1 for adjustment of transimpedance of MTI- amplifier (pull down)
SW2	input	d	input 2 for adjustment of transimpedance of MTI- amplifier (pull down)
SW3	input	d	input 3 for adjustment of transimpedance of MTI- amplifier (pull down)
PD	input	d	power down modus (pull down)
VOUT <n></n>	output	а	analog voltage output of amplifier channel n for
			X Y Z function of detector (see chapter 5)

a.) analog or digital

6.1 Adjustment of Transimpedance

settings of digital inputs			
SW1	SW1 SW2 SW3		transimpedance R
VDD	VDD	VDD	$20M\Omega - stage 1$
GND	VDD	VDD	$10M\Omega$ – stage 2
GND	VDD	GND	$5M\Omega$ – stage 3
VDD	GND	VDD	$2M\Omega - stage 4$
GND	GND	VDD	$1M\Omega$ – stage 5
VDD	GND	GND	500k Ω – stage 6
VDD	VDD	GND	100kΩ – stage 7
GND	GND	GND	$25k\Omega^{b}$ – stage 8

b.) default by pull down

6.2 Power Down Modus

settings of digital input				
PD = 1	bias current of	the IC		
VDD	< 8µA			
GND	typical ^c			
c.) default by pull down				
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7 SPECIFICATION

7.1 ELECTRICAL AND OPTICAL CHARACTERISTICS OF PHOTO DIODE ARRAY

 $(T_A = 25^{\circ}C; \text{ per single diode})$

Parameter	Symbol	Condition	min.	typ.	max.	Unit
Diameter of the light sensitivity area	D			2,0		mm
Light sensitivity area per single colour array (19 diodes)	A			0,76		mm²
		$\lambda_{z} = 445 \text{ nm}$	0,21	0,23	0,25	
Typical photo diode sensitivity		$\lambda_{\rm Y} = 555~{ m nm}$	0,30	0,33	0,36	A /\A/
of colour ranges	S _{max}	$\lambda_{Xk}=445~nm$	0,11	0,12	0,13	~, ••
		$\lambda_{\text{XI}}=600 \text{ nm}$	0,31	0,35	0,38	
Spectral tolerance of filter curve	Δλ(λ)				<1%*λ	nm
Reverse voltage	V _R		0	2,5	5	V
Dark current	I _R	$V_{R} = 2,5V$			10	рА
Noise equivalent power	NEP	$f_R = 100 \text{ Hz}$			<10 ⁻¹³	W/√H z
Cross-talk					<1	%
Angle of incidence	φ	$\Delta \lambda_{(Filter)} < 1\% * \lambda$			10	Grad

7.2 ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Condition	min.	typ.	max.	Unit
supply voltage	VDD		2.7	3 to 5	5.5	V
bias current MTI04	I(VDD)	27°C, VDD=5.5V		2.5	4.0	mA
bias current MTI04	I(VDD)	PD=VDD			8	μA
reference voltage	VREF		0.4		VDD-0.4	V

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7.3 AC/DC-Characteristics

Unless otherwise specified the data in this table is valid for $T_{OP} = 27^{\circ}C$ and VDD = 5V. All voltages are referenced to GND = 0V.

Parameter	Symbol	Condition	min.	typ.	max.	Unit
		stage 20MΩ	14000	20000	26700	kΩ
		stage 10MΩ	7000	10000	13350	kΩ
		stage 5MΩ	3500	5000	6700	kΩ
		stage 2MΩ	1400	2000	2670	kΩ
feedback resistor	R	stage 1MΩ	700	1000	1335	kΩ
		stage 0,5MΩ	350	500	670	kΩ
		stage 0,1MΩ	70	100	133	kΩ
		stage 0,025MΩ	17	25	34	kΩ
Typical photo sensitivity		$\lambda_{z} = 445 \text{ nm}$		34,9		
of colour ranges	S _{max}	$\lambda_{ m Y} = 555 \ nm$		50,1		V/
et etage 20MO		$\lambda_{Xk} = 445 \text{ nm}$		18,2		(µW/cm²)
al slage 20M12		$\lambda_{\chi l} = 600 \text{ nm}$		53,2		
		$\lambda_z = 445 \text{ nm}$		17,5		
rypical photo sensitivity		$\lambda_{\rm Y} = 555 \ \rm nm$		25,1		V/
of colour ranges	S _{max}	$\lambda_{\chi_k} = 445 \text{ nm}$		9,1		(µW/cm²)
at stage 10MΩ		$\lambda_{\rm XI} = 600 \ \rm nm$		26,6		
		$\lambda_z = 445 \text{ nm}$		8,7		
Typical photo sensitivity		$\lambda_{\rm Y} = 555 \ \rm nm$		12,5		V/
of colour ranges	S _{max}	$\lambda_{y_k} = 445 \text{ nm}$		4,5		(µW/cm²)
at stage 5MΩ		$\lambda_{\rm XI} = 600 \ \rm nm$		13,3		
		$\lambda_z = 445 \text{ nm}$		3,5		
Typical photo sensitivity		$\lambda_{\rm Y} = 555 \ \rm nm$		5,0		V/
of colour ranges	S _{max}	$\lambda_{xk} = 445 \text{ nm}$		1,8		(µW/cm²)
at stage 2MΩ		$\lambda_{\rm XI} = 600 \ \rm nm$		5,3		

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Parameter	Symbol	Condition		min.	typ.	max.	Unit				
Typical photo sensitivity		$\lambda_{Z} = 445 \text{ nm}$			1,75						
of colour ranges	e	$\lambda_{Y} = 555 \text{ nm}$			2,51		V/				
at stage 1MO	S _{max}	$\lambda_{Xk} = 445 \text{ nm}$			0,91		(µW/cm²)				
		$\lambda_{\chi I}=600~nm$			2,66						
Typical photo sensitivity		$\lambda_{Z} = 445 \text{ nm}$			0,874						
of colour ranges	e	$\lambda_{\rm Y} = 555~{\rm nm}$			1,254		V/				
at stage 0.5MO	O _{max}	$\lambda_{\chi_k} = 445 \text{ nm}$			0,456		(µW/cm²)				
		$\lambda_{XI}=600~nm$			1,330						
Typical photo sensitivity		$\lambda_{z} = 445 \text{ nm}$			0,175						
of colour ranges	c.	$\lambda_{\rm Y} = 555~{\rm nm}$			0,251		V/				
at stage 0 1MO	S _{max}	$\lambda_{Xk} = 445 \text{ nm}$			0,091		(µW/cm²)				
at stage 0, IMM2		$\lambda_{XI}=600~\text{nm}$			0,266						
Typical photo sensitivity		$\lambda_{z} = 445 \text{ nm}$			0,044						
of colour ranges	S _{max}	$\lambda_{\rm Y} = 555~{\rm nm}$			0,063		V/				
at stage 0.025MO		$\lambda_{Xk} = 445 \text{ nm}$			0,023		(µW/cm²)				
		$\lambda_{XI}=600~nm$			0,067						
		stage 20MΩ, T _{op}		4	6	16	kHz				
		stage 10MΩ, T _{op}		7	11	28	kHz				
		stage 5MΩ, T _{op}		11	16	42	kHz				
signal frequency	f _{3dB}	stage 2MΩ, T _{op}		18	26	66	kHz				
		stage 1MΩ, T _{op}		25	35	95	kHz				
		stage 0,5MΩ, T _o	P	35	50	130	kHz				
		stage 0,1MΩ, T _o	P	80	120	280	kHz				
		stage 0,025MΩ,	T _{OP}	160	300	580	kHz				
temperature coefficient of the feedback resistor	TC _R				-3300		ppm/K				
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Parameter	Symbol	Condition		min.	typ.	max.	Unit
offset voltage	V_{OFF}^{4}	T _{OP}		-10		10	mV
capacitive load at VOUT <x></x>	C _{LOAD}	I _{LOAD} < 0.5mA per output				50	pF
pull down current SW1, SW2, SW3, SW4, PD	I _{PDPAD}	digital inputs				200	μΑ
tolerance of the feedback resistors between the four channels	TOL _R ⁵	DC input curren	ıt;	1		10	%

7.4 Maximum Conditions

Violations of absolute maximum conditions are not allowed under any circumstances, otherwise the IC can be destroyed. All voltages are referenced to GND = 0V.

Parameter	Symbol	min.	max.	Unit
power supply	VDD	0.3	7.0	V
input and output voltages	\Rightarrow IC-pinning	0.3	VDD+0.3	V
power dissipation	POP		0.025	W
operating temperature	ТОР	-40	+ 100	°C
storage temperature	TSTG	-40	+ 100	°C

 4 V_{OFF} = VOUT < X > - VREF; results from input offset voltage and input leakage current 5 up to max. 1% available on request

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8 PACKAGE AND OUTLINE DIMENSIONS



Figure 7: Sizes of packaged TIAM2

Туре	H1+H2	H1	H2	L	L1	L2	В	B1	B2
Α	6,50	6,00 ⁶	0,50	6,50	2,00	0,95	5,00	1,50	2,00
В	2,00	1,50 ⁷	0,50	6,50	2,00	0,95	5,00	1,50	2,00
Tol.	±0,20	±0,10	±0,10	±0,05	±0,05	±0,05	±0,05	±0,05	±0,05

All dimensions in mm



 ⁶ specific variant for prototypes (only with 4,0 mm thickness of windows cap) or custom specific on request
 ⁷ standard device for series

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Figure 9: PIN configuration TIAM2 - Bottom view



Figure 10: PIN configuration MTCS-TIAM2 Top View

9 PIN-CONFIGURATION

Pin	Name	IN-/OUTPUT	A/D	Description
1	PD	INPUT	D	power down modus (pull down)
2	VOUT Y	OUTPUT	А	analogue voltage output Y
3	VOUT Z	OUTPUT	А	analogue voltage output Z
4	VOUT X	OUTPUT	А	analogue voltage output X
5	SW3	INPUT	D	input 3 for adjustment of transimpedance of MTI-amplifier (pull down)
6	VDD	INPUT	D/A	power supply
7	SW2	INPUT	D	input 2 for adjustment of transimpedance of MTI-amplifier (pull down)
8	SW1	INPUT	D	input 1 for adjustment of transimpedance of MTI-amplifier (pull down)
9	GND	INPUT	D/A	ground
10	VREF	INPUT	Α	reference voltage

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12 ORDERING INFORMATION

True Colour sensor with integrated amplifier

MTCS-TIAM2

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